

2SK1455

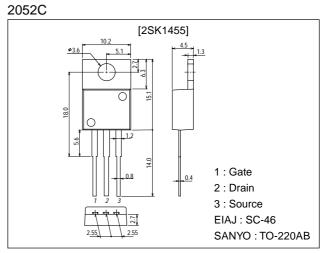
Ultrahigh-Speed Switching Applications

Features

- · Low ON-state resistance.
- · Ultrahigh-speed switching.
- \cdot Converters.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		900	V
Gate-to-Source Voltage	VGSS		±30	V
Drain Current (DC)	۱ _D		0.2	А
Drain Current (Pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	0.4	А
Allowable Power Dissipation	P-	Tc=25°C	30	W
	PD		1.75	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Unit
V(BR)DSS	I _D =1mA, V _{GS} =0	900			V
IDSS	V _{DS} =900V, V _{GS} =0			1.0	mA
IGSS	V _{GS} =±30V, V _{DS} =0			±100	nA
VGS(off)	V _{DS} =10V, I _D =1mA	2.0		3.0	V
yfs	V _{DS} =20V, I _D =0.1A	0.08	0.15		S
R _{DS(on)}	I _D =0.1A, V _{GS} =10V		50	70	Ω
	V _{(BR)DSS} I _{DSS} I _{GSS} V _{GS(off)} yfs	V(BR)DSS ID=1mA, VGS=0 IDSS VDS=900V, VGS=0 IGSS VGS=±30V, VDS=0 VGS(off) VDS=10V, ID=1mA yfs VDS=20V, ID=0.1A	V(BR)DSS ID=1mA, VGS=0 900 IDSS VDS=900V, VGS=0 900 IGSS VGS=±30V, VDS=0 900 VGS(off) VDS=10V, ID=1mA 2.0 I yfs VDS=20V, ID=0.1A 0.08	Symbol Conditions min typ V(BR)DSS ID=1mA, VGS=0 900 900 IDSS VDS=900V, VGS=0 1000 1000 IGSS VGS=±30V, VDS=0 1000 1000 VGS(off) VDS=10V, ID=1mA 2.0 1000 I yfs VDS=20V, ID=0.1A 0.08 0.15	Symbol Conditions min typ max V(BR)DSS Ip=1mA, V_GS=0 900 900 1.0 IDSS VDS=900V, V_GS=0 1.0 1.0 IGSS VGS=±30V, VDS=0 ±100 VGS(off) VDS=10V, Ip=1mA 2.0 3.0 I yfs I VDS=20V, Ip=0.1A 0.08 0.15

(Note) Be careful in handling the 2SK1455 because it has no protection diode between gate and source.

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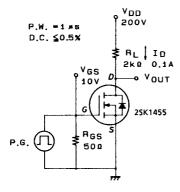
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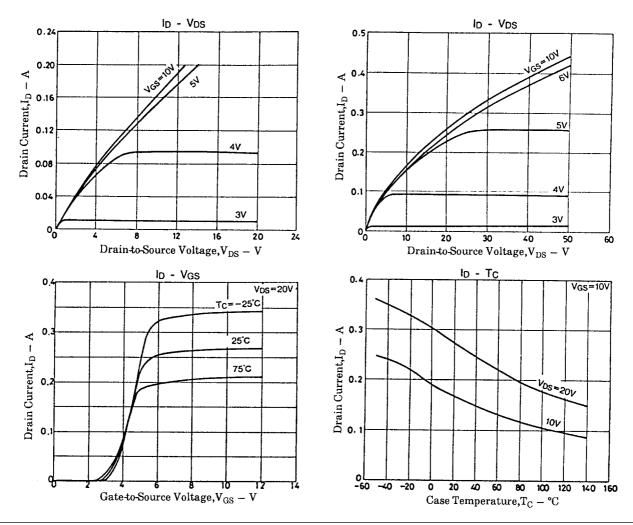
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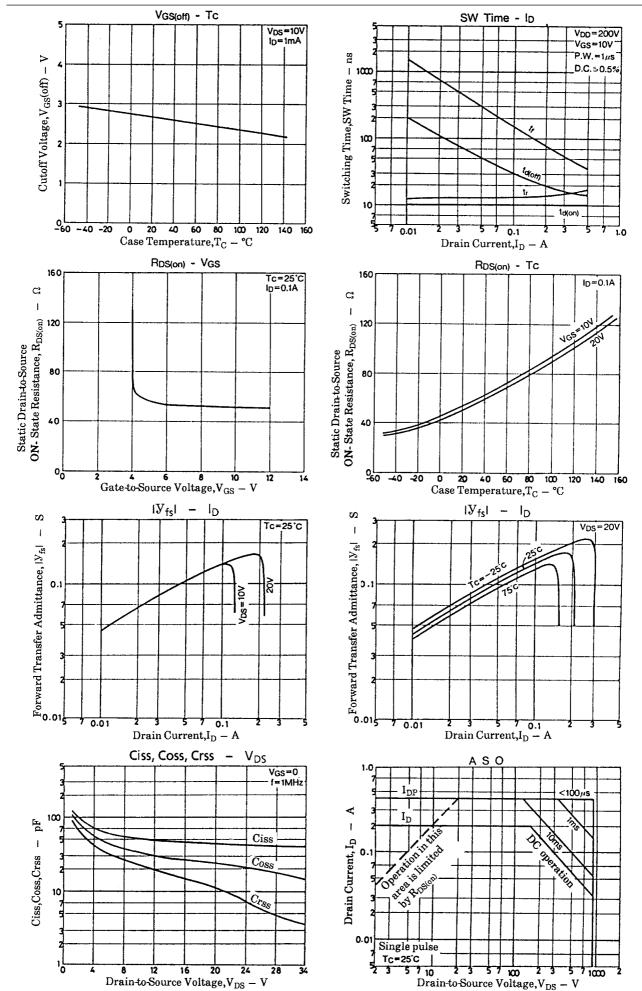
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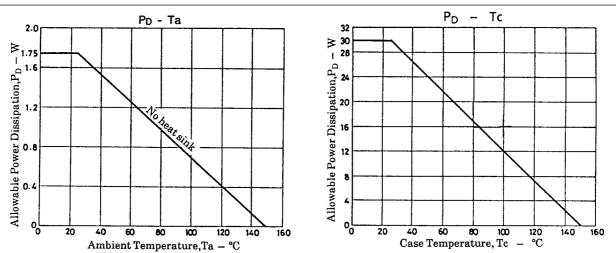
Parameter	Symbol	Conditions	Ratings			Unit
Falanetei			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		45		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		25		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		10		pF
Turn-ON Delay Time	^t d(on)	I_{D} =0.1A, V_{GS} =10V, V_{DD} =200V, R_{GS} =50 Ω		10		ns
Rise Time	tr	I_{D} =0.1A, V_{GS} =10V, V_{DD} =200V, R_{GS} =50 Ω		15		ns
Turn-OFF Delay Time	^t d(off)	$I_D=0.1A$, $V_{GS}=10V$, $V_{DD}=200V$, $R_{GS}=50\Omega$		30		ns
Fall Time	t _f	$I_D=0.1A$, $V_{GS}=10V$, $V_{DD}=200V$, $R_{GS}=50\Omega$		180		ns
Diode Forward Voltage	V _{SD}	I _S =0.2A, V _{GS} =0			1.8	V

Switching Time Test Circuit









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